

Model 310-SL-02 series Bare Die (Flip chip form, AuSn Pad)

Typical Optical-Electrical Characteristics

 $(I_{F}=350 \text{mA}, T_{a}=25^{\circ}\text{C})$

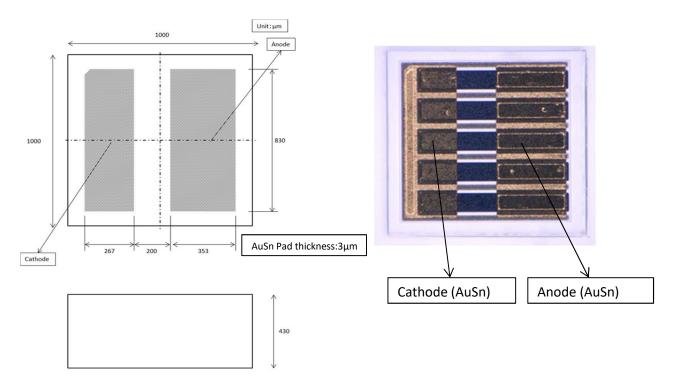
ltem		Symbol	Unit	310-SL-02-C		
				Min	Тур	Max
Peak Wavelength	(*)	λ _p	nm	305	310	315
Radiant Flux	(**)	Po	mW	50	70	-
Full Width at Half Maximum		⊿λ	nm	-	15	20
Forward Voltage		V_{F}	V	-	6.0	-

(*)Peak Wavelength Measurement tolerance is ±3nm.

(**)Radiant Flux Measurement tolerance is ±10%.

Specification and dimension are subject to change for improvement without notice.

Product ID, Physical dimensions 310-SL-02-C Bare Die







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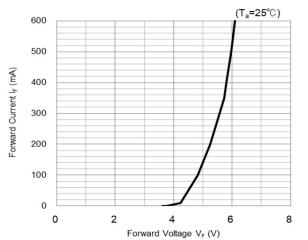
Absolute Maximum Ratings

ltem	Symbol	Unit	Value
Forward Current	I _F	mA	600
Junction Temperature	TJ	°C	100
Operating Temperature	T _{OPR}	°C	-30 ~ +85
Storage Temperature	T _{STR}	°C	-40 \sim +85 (No condensation)

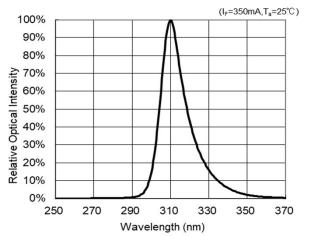
800 700 (30,600) 600 Forward Current : IF(mA) 500 400 300 200 (85,100) 100 0 0 20 40 60 80 100 Ambient Temperature : Ta(deg)

Derating Curve

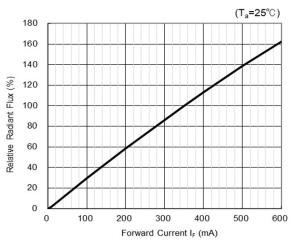
Forward Voltage vs Forward Current



Spectrum



Forward Current vs Radiant Flux



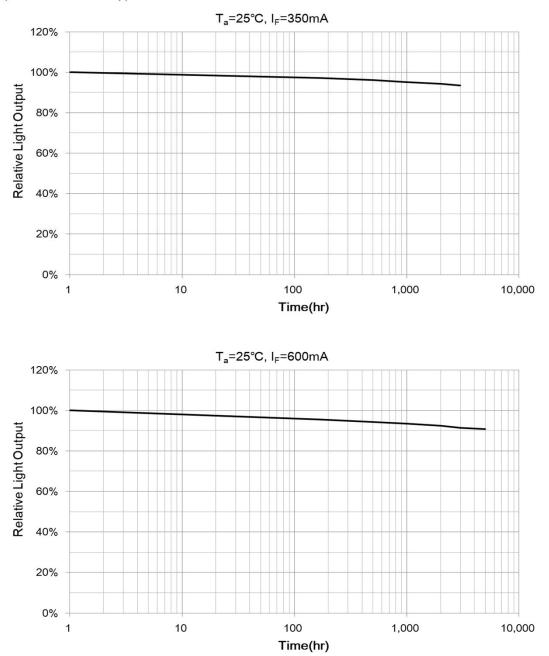
DOWA Electronics Materials Co., Ltd.



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Life Expectacy Data

(for reference only)



This life data was measured with the AIN submount on AI-substrate and fan.